NSN 5961-01-363-1085

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-363-1085 **Inclosure Material:** Metal **Overall Length:** 5.2 millimeters **Overall Diameter:** 2.5 millimeters **Mounting Method:** Clip **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 1.0 reverse voltage, instantaneous and 3.3 regulator voltage, dc and 1.2 forward voltage, dc **Current Rating Per Characteristic:** 100.00 microamperes forward current, average peak and 76.00 milliamperes all primaries horsepower metric **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: